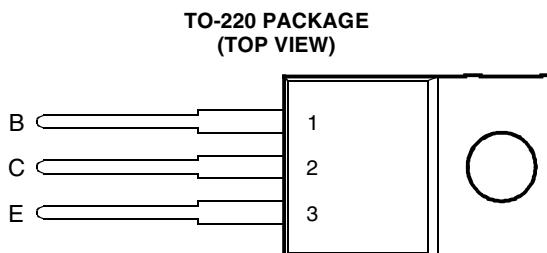


- Designed for Complementary Use with TIP125, TIP126 and TIP127
- 65 W at 25°C Case Temperature
- 5 A Continuous Collector Current
- Minimum h_{FE} of 1000 at 3 V, 3 A

! This series is obsolete and not recommended for new designs.



Pin 2 is in electrical contact with the mounting base.

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absolute maximum ratings at 25°C case temperature (unless otherwise noted)

| RATING | | SYMBOL | VALUE | UNIT |
|--|--------|---------------------|-------------|------|
| Collector-base voltage ($I_E = 0$) | TIP120 | V_{CBO} | 60 | V |
| | TIP121 | V_{CBO} | 80 | |
| | TIP122 | V_{CBO} | 100 | |
| Collector-emitter voltage ($I_B = 0$) | TIP120 | V_{CEO} | 60 | V |
| | TIP121 | V_{CEO} | 80 | |
| | TIP122 | V_{CEO} | 100 | |
| Emitter-base voltage | | V_{EBO} | 5 | V |
| Continuous collector current | | I_C | 5 | A |
| Peak collector current (see Note 1) | | I_{CM} | 8 | A |
| Continuous base current | | I_B | 0.1 | A |
| Continuous device dissipation at (or below) 25°C case temperature (see Note 2) | | P_{tot} | 65 | W |
| Continuous device dissipation at (or below) 25°C free air temperature (see Note 3) | | P_{tot} | 2 | W |
| Unclamped inductive load energy (see Note 4) | | $\frac{1}{2}LI_C^2$ | 50 | mJ |
| Operating junction temperature range | | T_j | -65 to +150 | °C |
| Storage temperature range | | T_{stg} | -65 to +150 | °C |
| Lead temperature 3.2 mm from case for 10 seconds | | T_L | 260 | °C |

NOTES: 1. This value applies for $t_p \leq 0.3$ ms, duty cycle $\leq 10\%$.

2. Derate linearly to 150°C case temperature at the rate of 0.52 W/°C.

3. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.

4. This rating is based on the capability of the transistor to operate safely in a circuit of: $L = 20$ mH, $I_{B(on)} = 5$ mA, $R_{BE} = 100$ Ω, $V_{BE(off)} = 0$, $R_S = 0.1$ Ω, $V_{CC} = 20$ V.

PRODUCT INFORMATION

electrical characteristics at 25°C case temperature

| PARAMETER | TEST CONDITIONS | | | MIN | TYP | MAX | UNIT | |
|---------------|---|--------------------------|-----------------------|----------------------------|-----------------|-----|------|----|
| $V_{(BR)CEO}$ | Collector-emitter breakdown voltage (see Note 5) | $I_C = 30 \text{ mA}$ | $I_B = 0$ | TIP120 TIP121 TIP122 | 60 80 100 | | | V |
| I_{CEO} | Collector-emitter cut-off current | $V_{CE} = 30 \text{ V}$ | $I_B = 0$ | TIP120 | | 0.5 | | |
| | | $V_{CE} = 40 \text{ V}$ | $I_B = 0$ | TIP121 | | 0.5 | | mA |
| | | $V_{CE} = 50 \text{ V}$ | $I_B = 0$ | TIP122 | | 0.5 | | |
| I_{CBO} | Collector cut-off current | $V_{CB} = 60 \text{ V}$ | $I_E = 0$ | TIP120 | | 0.2 | | |
| | | $V_{CB} = 80 \text{ V}$ | $I_E = 0$ | TIP121 | | 0.2 | | mA |
| | | $V_{CB} = 100 \text{ V}$ | $I_E = 0$ | TIP122 | | 0.2 | | |
| I_{EBO} | Emitter cut-off current | $V_{EB} = 5 \text{ V}$ | $I_C = 0$ | | | 2 | | mA |
| h_{FE} | Forward current transfer ratio | $V_{CE} = 3 \text{ V}$ | $I_C = 0.5 \text{ A}$ | (see Notes 5 and 6) | 1000 | | | |
| | | $V_{CE} = 3 \text{ V}$ | $I_C = 3 \text{ A}$ | | 1000 | | | |
| $V_{CE(sat)}$ | Collector-emitter saturation voltage | $I_B = 12 \text{ mA}$ | $I_C = 3 \text{ A}$ | (see Notes 5 and 6) | | 2 | | V |
| | | $I_B = 20 \text{ mA}$ | $I_C = 5 \text{ A}$ | | | 4 | | |
| V_{BE} | Base-emitter voltage | $V_{CE} = 3 \text{ V}$ | $I_C = 3 \text{ A}$ | (see Notes 5 and 6) | | 2.5 | | V |
| V_{EC} | Parallel diode forward voltage | $I_E = 5 \text{ A}$ | $I_B = 0$ | | | 3.5 | | V |

NOTES: 5. These parameters must be measured using pulse techniques, $t_p = 300 \mu\text{s}$, duty cycle $\leq 2\%$.

6. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

thermal characteristics

| PARAMETER | MIN | TYP | MAX | UNIT |
|---|-----|-----|------|------|
| $R_{\theta JC}$ Junction to case thermal resistance | | | 1.92 | °C/W |
| $R_{\theta JA}$ Junction to free air thermal resistance | | | 62.5 | °C/W |

resistive-load-switching characteristics at 25°C case temperature

| PARAMETER | TEST CONDITIONS [†] | | | MIN | TYP | MAX | UNIT |
|-------------------------|------------------------------|-----------------------------|--|-----|-----|-----|------|
| t_{on} Turn-on time | $I_C = 3 \text{ A}$ | $I_{B(on)} = 12 \text{ mA}$ | $I_{B(off)} = -12 \text{ mA}$ | | 1.5 | | μs |
| t_{off} Turn-off time | $V_{BE(off)} = -5 \text{ V}$ | $R_L = 10 \Omega$ | $t_p = 20 \mu\text{s}, \text{dc} \leq 2\%$ | | 8.5 | | μs |

† Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

PRODUCT INFORMATION

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TYPICAL CHARACTERISTICS

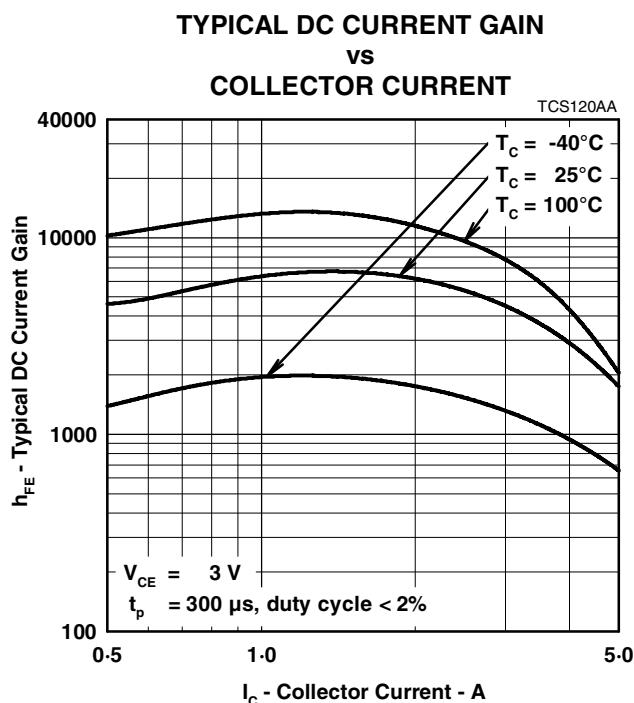


Figure 1.

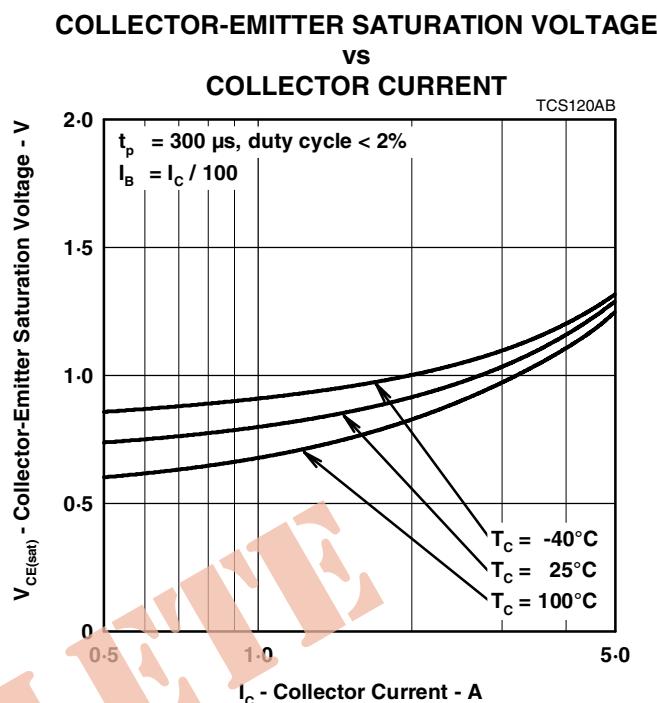


Figure 2.

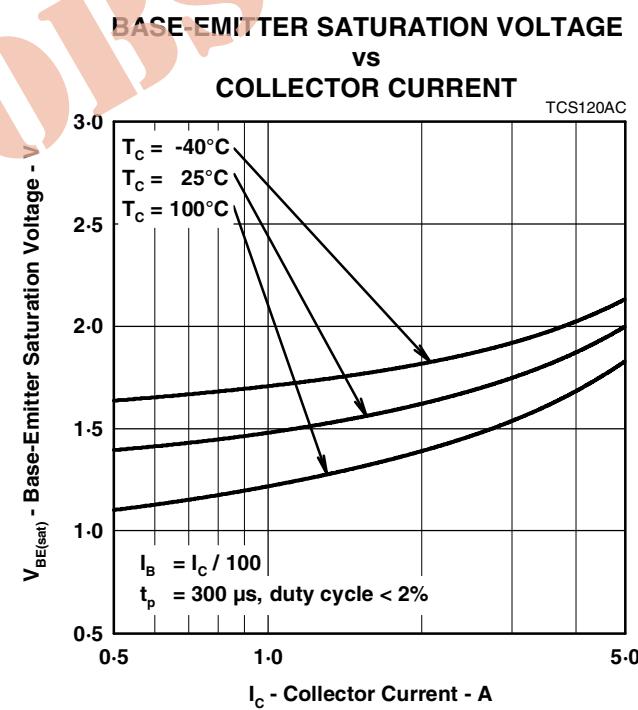


Figure 3.

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MAXIMUM SAFE OPERATING REGIONS

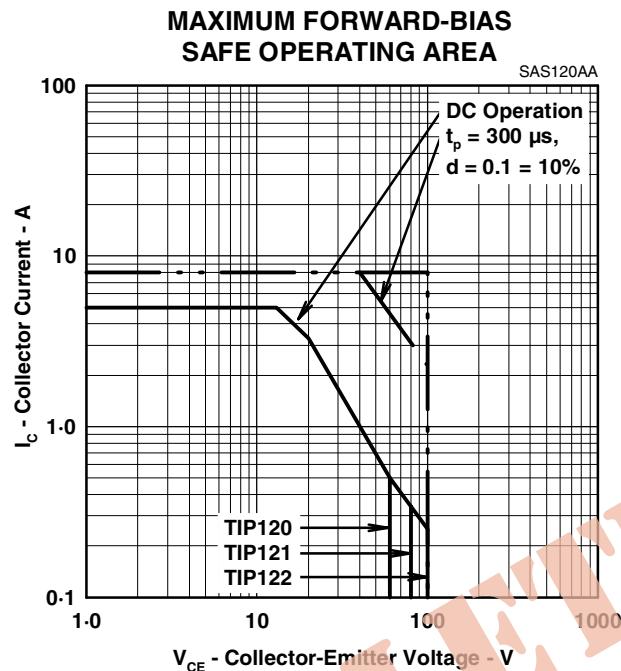


Figure 4.

THERMAL INFORMATION

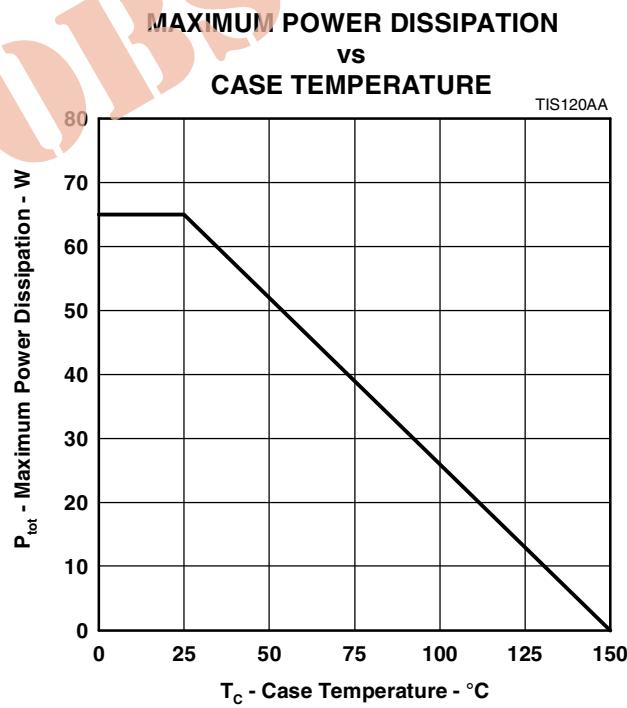


Figure 5.

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